SCES491C - SEPTEMBER 2003 - REVISED JANUARY 2008

•	D OR PW PACKAGE (TOP VIEW)
	$\begin{array}{c c} 1 \\ 1 \\ 1B \\ 1B \\ 12 \\ 13 \\ 14B \end{array}$
<ul> <li>Operates From 1.65 V to 3.6 V</li> </ul>	1Y 13 12 4A
<ul> <li>Max t<sub>pd</sub> of 2.9 ns at 3.3 V</li> </ul>	2A 🛛 4 11 🗍 4Y
• ±24-mA Output Drive at 3.3 V	2B 🛛 5 10 🗋 3B
<ul> <li>Latch-Up Performance Exceeds 250 mA Per JESD 17</li> </ul>	2Y [ 6 9 ] 3A GND [ 7 8 ] 3Y

#### description/ordering information

The SN74ALVC08 quadruple 2-input positive-AND gate is designed for 1.65-V to 3.6-V V<sub>CC</sub> operation.

The device performs the Boolean function  $Y = A \bullet B$  or  $Y = \overline{\overline{A} + \overline{B}}$  in positive logic.

P-SIDE ARKING
180
)

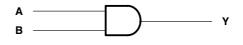
#### **ORDERING INFORMATION<sup>†</sup>**

<sup>†</sup> For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at http://www.ti.com.

<sup>‡</sup> Package drawings, thermal data, and symbolization are available at http://www.ti.com/packaging.

FU	FUNCTION TABLE (each gate)										
INP	UTS	OUTPUT									
Α	В	Y									
н	Н	Н									
L	Х	L									
Х	L	L									

logic diagram, each gate (positive logic)





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#### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)<sup>†</sup>

Input voltage range, V <sub>I</sub> (see Note 1) Output voltage range, V <sub>O</sub> (see Notes 1 and 2) Input clamp current, I <sub>IK</sub> (V <sub>I</sub> < 0) Output clamp current, I <sub>OK</sub> (V <sub>O</sub> < 0) Continuous output current, I <sub>O</sub> Continuous current through V <sub>CC</sub> or GND Package thermal impedance, $\theta_{JA}$ (see Note 3): D	-0.5 V to 4.6 V -0.5 V to 4.6 V -0.5 V to 4.6 V -0.5 V to V <sub>CC</sub> + 0.5 V -50 mA ±50 mA ±100 mA package 86°C/W W package 113°C/W
	-65°C to 150°C

<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output current ratings are observed.

2. This value is limited to 4.6 V maximum.

3. The package thermal impedance is calculated in accordance with JESD 51-7.

#### recommended operating conditions (see Note 4)

			MIN	МАХ	UNIT	
V <sub>CC</sub>	Supply voltage		1.65	3.6	V	
		V <sub>CC</sub> = 1.65 V to 1.95 V	$0.65  imes V_{CC}$			
VIH	High-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	1.7		V	
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	2			
		V <sub>CC</sub> = 1.65 V to 1.95 V		$0.35 \times V_{CC}$		
VIL	Low-level input voltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.7	V	
		V <sub>CC</sub> = 2.7 V to 3.6 V		0.8		
VI	Input voltage	·	0	3.6	V	
Vo	Output voltage		0	V <sub>CC</sub>	V	
		V <sub>CC</sub> = 1.65 V		-4		
		V <sub>CC</sub> = 2.3 V		-12		
I <sub>OH</sub>	High-level output current	V <sub>CC</sub> = 2.7 V		-12	mA	
		V <sub>CC</sub> = 3 V		-24		
		V <sub>CC</sub> = 1.65 V		4		
		V <sub>CC</sub> = 2.3 V		12		
I <sub>OL</sub>	Low-level output current	V <sub>CC</sub> = 2.7 V		12	mA	
		V <sub>CC</sub> = 3 V		24	1	
$\Delta t / \Delta v$	Input transition rise or fall rate	·		5	ns/V	
T <sub>A</sub>	Operating free-air temperature		-40	85	°C	

NOTE 4: All unused inputs of the device must be held at V<sub>CC</sub> or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.



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PARAMETER	TEST CONDITI	ONS	V <sub>CC</sub>	MIN	TYP <sup>†</sup>	MAX	UNIT			
	I <sub>OH</sub> = -100 μA		1.65 V to 3.6 V	V <sub>CC</sub> -0.2	2					
	$I_{OH} = -4 \text{ mA}$		1.65 V	1.2						
	I <sub>OH</sub> = -6 mA		2.3 V	2						
V <sub>OH</sub>			2.3 V	1.7			V			
	I <sub>OH</sub> = -12 mA		2.7 V	2.2						
			3 V	2.4						
	I <sub>OH</sub> = -24 mA		3 V	2						
	I <sub>OL</sub> = 100 μA		1.65 V to 3.6 V			0.2				
	I <sub>OL</sub> = 4 mA		1.65 V			0.45				
	I <sub>OL</sub> = 6 mA		2.3 V			0.4				
V <sub>OL</sub>			2.3 V			0.7	V			
	I <sub>OL</sub> = 12 mA		2.7 V			0.4				
	I <sub>OL</sub> = 24 mA		3 V			0.55				
li -	V <sub>I</sub> = V <sub>CC</sub> or GND		3.6 V			±5	μA			
I <sub>CC</sub>	$V_{I} = V_{CC}$ or GND, $I_{O} =$	0	3.6 V			10	μA			
$\Delta I_{CC}$	One input at V <sub>CC</sub> – 0.6 V, Othe	er inputs at V <sub>CC</sub> or GND	3 V to 3.6 V			750	μA			
C <sub>i</sub>	$V_{I} = V_{CC}$ or GND		3.3 V		4.5		pF			

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

<sup>†</sup> All typical values are at  $V_{CC} = 3.3$  V,  $T_A = 25^{\circ}$ C.

# switching characteristics over recommended operating free-air temperature range (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	V <sub>CC</sub> = 1.8 V ± 0.15 V		$V_{CC}$ = 2.5 V ± 0.2 V		V <sub>CC</sub> = 2.7 V		V <sub>CC</sub> = 3.3 V ± 0.3 V		UNIT
	(INPUT)	(001901)	MIN	MAX	MIN	MAX	MIN	MAX	MIN	MAX	
t <sub>pd</sub>	A or B	Y	1.2	5.3	1	3.2		3	1	2.9	ns

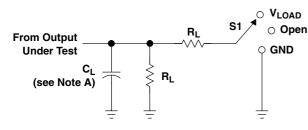
### operating characteristics, $T_A = 25^{\circ}C$

	PARAMETER	TEOTO		V <sub>CC</sub> = 1.8 V	V <sub>CC</sub> = 2.5 V	V <sub>CC</sub> = 3.3 V	
	FARAMETER	TESTC	ONDITIONS	ТҮР	ТҮР	ТҮР	UNIT
$C_{\text{pd}}$	Power dissipation capacitance per gate	$C_{L} = 0,$	f = 10 MHz	24	25	26	pF



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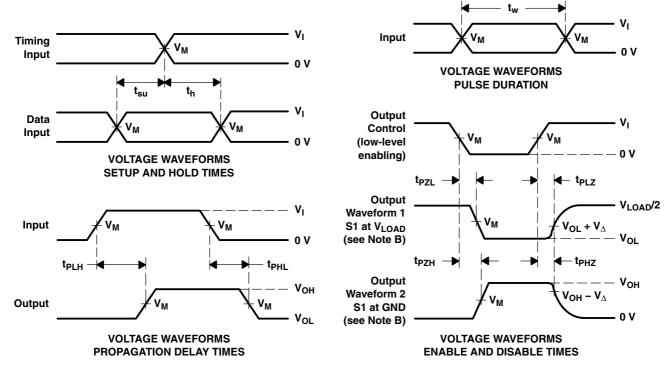




LOAD CIRCUIT

TEST	S1
t <sub>pd</sub>	Open
t <sub>PLZ</sub> /t <sub>PZL</sub>	V <sub>LOAD</sub>
t <sub>PHZ</sub> /t <sub>PZH</sub>	GND

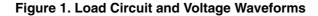
M	INPUT		INPUT		INPUT		, v	V	•		V
V <sub>CC</sub>	VI	t <sub>r</sub> /t <sub>f</sub>	VM	V <sub>LOAD</sub>	C∟	RL	$V_{\Delta}$				
1.8 V $\pm$ 0.15 V	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>1 k</b> Ω	0.15 V				
$\textbf{2.5}\pm\textbf{0.2}~\textbf{V}$	V <sub>CC</sub>	≤2 ns	V <sub>CC</sub> /2	$2 \times V_{CC}$	30 pF	<b>500</b> Ω	0.15 V				
2.7 V	2.7 V	≤2.5 ns	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V				
3.3 V $\pm$ 0.3 V	2.7 V	≤ <b>2.5 ns</b>	1.5 V	6 V	50 pF	<b>500</b> Ω	0.3 V				



NOTES: A. C<sub>1</sub> includes probe and jig capacitance.

B. Waveform 1 is for an output with internal conditions such that the output is low, except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high, except when disabled by the output control. C. All input pulses are supplied by generators having the following characteristics: PRR  $\leq$  10 MHz, Z<sub>Q</sub> = 50  $\Omega$ .

- D. The outputs are measured one at a time, with one transition per measurement.
- E.  $t_{PLZ}$  and  $t_{PHZ}$  are the same as  $t_{dis}$ .
- F. t<sub>PZL</sub> and t<sub>PZH</sub> are the same as t<sub>en</sub>.
- G.  $t_{PLH}$  and  $t_{PHL}$  are the same as  $t_{pd}$ .
- H. All parameters and waveforms are not applicable to all devices.





24-Jan-2013

#### PACKAGING INFORMATION

Orderable Device	Status	Package Type	•		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
SN74ALVC08IDRG4Q1	ACTIVE	SOIC	D	14	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	ALVC08I	Samples
SN74ALVC08IDRQ1	OBSOLETE	SOIC	D	14		TBD	Call TI	Call TI	-40 to 85	ALVC08I	
SN74ALVC08IPWRG4Q1	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA08I	Samples
SN74ALVC08IPWRQ1	ACTIVE	TSSOP	PW	14	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	-40 to 85	VA08I	Samples

<sup>(1)</sup> The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free (RoHS):** TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

<sup>(3)</sup> MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

<sup>(4)</sup> Only one of markings shown within the brackets will appear on the physical device.

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# PACKAGE OPTION ADDENDUM

24-Jan-2013

#### OTHER QUALIFIED VERSIONS OF SN74ALVC08-Q1 :

Catalog: SN74ALVC08

• Enhanced Product: SN74ALVC08-EP

NOTE: Qualified Version Definitions:

- Catalog TI's standard catalog product
- Enhanced Product Supports Defense, Aerospace and Medical Applications

# PACKAGE MATERIALS INFORMATION

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#### TAPE AND REEL INFORMATION





### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal												
Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74ALVC08IPWRG4Q1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1
SN74ALVC08IPWRQ1	TSSOP	PW	14	2000	330.0	12.4	6.9	5.6	1.6	8.0	12.0	Q1

TEXAS INSTRUMENTS

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# PACKAGE MATERIALS INFORMATION

14-Mar-2013



\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
SN74ALVC08IPWRG4Q1	TSSOP	PW	14	2000	367.0	367.0	35.0
SN74ALVC08IPWRQ1	TSSOP	PW	14	2000	367.0	367.0	35.0

D (R-PDSO-G14)

PLASTIC SMALL OUTLINE



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AB.



PW (R-PDSO-G14)

PLASTIC SMALL OUTLINE



A. An integration of the information o

Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.

Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.

E. Falls within JEDEC MO-153



# PW (R-PDSO-G14)

# PLASTIC SMALL OUTLINE



- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



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